

### General Description

The MP1580 is a monolithic step down switch mode converter with a built in internal Power MOSFET. It achieves 2A continuous output current over a wide input supply range with excellent load and line regulation.

Current mode operation provides fast transient response and eases loop stabilization.

Fault condition protection includes cycle-by-cycle current limiting and thermal shutdown. In shutdown mode the regulator draws 23 $\mu$ A of supply current.

The MP1580 requires a minimum number of readily available standard external components. A synchronization pin allows the part to be driven to 600KHz.

### Ordering Information

| Part Number *          | Package          | Temperature    |
|------------------------|------------------|----------------|
| MP1580HS               | SOIC8            | -40 to +125 °C |
| <a href="#">EV0007</a> | Evaluation Board |                |

\* For Tape & Reel use suffix - Z (e.g. MP1580HS-Z)

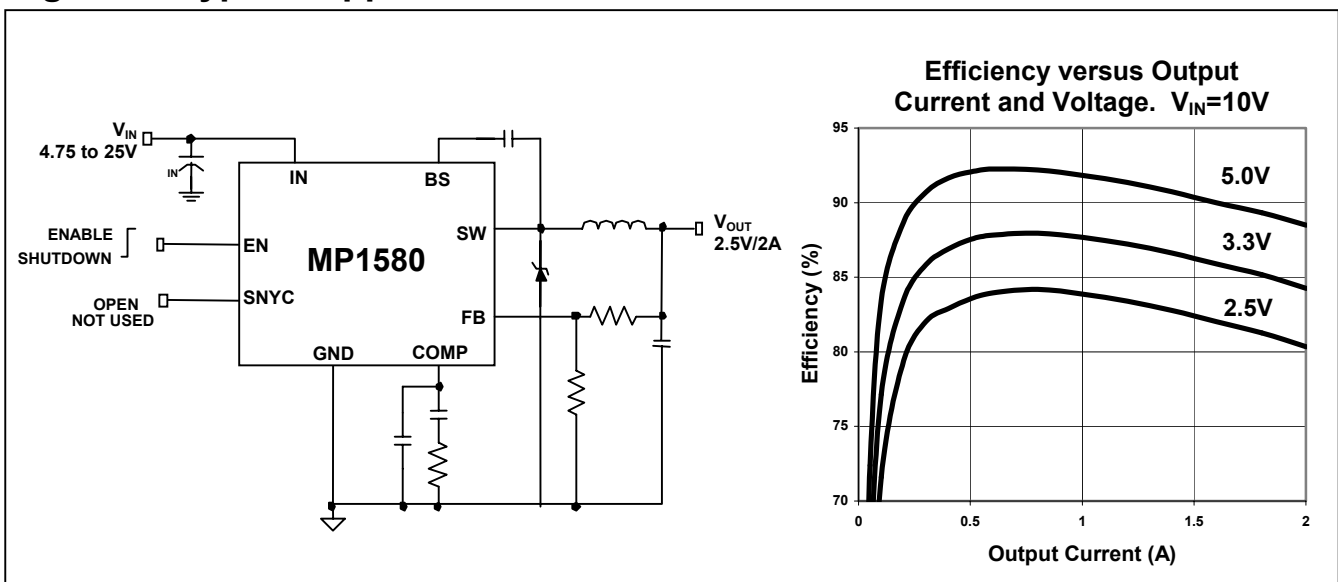
### Features

- 2A Output Current
- 0.18 $\Omega$  Internal Power MOSFET Switch
- Stable with Low ESR Output Ceramic capacitors
- Up to 95% Efficiency
- 20 $\mu$ A Shutdown Mode
- Fixed 380KHz frequency
- Thermal Shutdown
- Cycle-by-cycle over current protection
- Wide 4.75 to 25V operating input range
- Output Adjustable from 1.22 to 21V
- Programmable under voltage lockout
- Frequency Synchronization Input
- Available in 8 pin SO package
- **Evaluation Board Available**

### Applications

- Distributed Power Systems
- Battery Charger
- Pre-Regulator for Linear Regulators

**Figure 1: Typical Application Circuit**



| <b>Absolute Maximum Ratings (Note 1)</b> |                      | <b>Recommended Operating Conditions (Note 2)</b> |               |
|--|----------------------|--|---------------|
| Supply Voltage ( $V_{IN}$ )              | 28V                  | Input Voltage ( $V_{IN}$ )                       | 4.75V to 25V  |
| Switch Voltage ( $V_{SW}$ )              | -1V to $V_{IN} + 1V$ | Operating Temperature                            | -40 to +125°C |
| Boost Voltage                            | $V_{SW} + 6V$        |  |               |
| Feedback Voltage ( $V_{FB}$ )            | -0.3 to 6V           |  |               |
| Enable/UVLO Voltage ( $V_{EN}$ )         | -0.3 to 6V           |  |               |
| Comp Voltage ( $V_{COMP}$ )              | -0.3 to 6V           |  |               |
| Sync Voltage ( $V_{SYNC}$ )              | -0.3 to 6V           |  |               |
| Junction Temperature                     | 150°C                | <b>Package Thermal Characteristics (Note 3)</b>  |               |
| Lead Temperature                         | 260°C                | Thermal Resistance $\theta_{JA}$ (SOIC8)         | 105°C/W       |
| Storage Temperature                      | -65 to +150°C        |  |               |

**Electrical Characteristics** (Unless otherwise specified  $V_{IN}=12V$ ,  $T_A=25^\circ C$ )

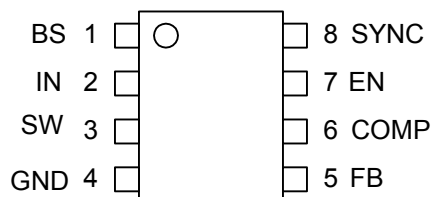
| Parameters  | Condition                                       | Min   | Typ   | Max   | Units     |
|---|---|-------|-------|-------|-----------|
| Feedback Voltage  | $4.75V \leq V_{IN} \leq 25V$<br>$V_{COMP} < 2V$ | 1.198 | 1.222 | 1.246 | V         |
| Upper Switch On Resistance                                |   |       | 0.18  |       | $\Omega$  |
| Lower Switch On Resistance                                |   |       | 10    |       | $\Omega$  |
| Upper Switch Leakage                                      | $V_{EN}=0V$ ; $V_{SW}=0V$                       |       | 0     | 10    | $\mu A$   |
| Current Limit   |   | 2.4   | 2.85  | 3.3   | A         |
| Current Limit Gain.<br>Output Current to Comp Pin Voltage |   |       | 1.95  |       | A/V       |
| Error Amplifier Voltage Gain                              |   |       | 400   |       | V/V       |
| Error Amplifier Transconductance                          | $\Delta I_C = \pm 10 \mu A$                     | 500   | 770   | 1100  | $\mu Mho$ |
| Oscillator Frequency                                      |   | 342   | 380   | 418   | KHz       |
| Short Circuit Frequency                                   | $V_{FB} = 0V$                                   | 30    | 42    | 54    | KHz       |
| Sync Frequency  | Sync Drive 0 to 2.7V                            | 445   |       | 600   | KHz       |
| Maximum Duty Cycle  | $V_{FB} = 1.0V$                                 |       | 90    |       | %         |
| Minimum Duty Cycle  | $V_{FB} = 1.5V$                                 |       |       | 0     | %         |
| Enable Threshold  | $I_{CC} > 100\mu A$                             | 0.7   | 1.0   | 1.3   | V         |
| Enable Pull Up Current                                    | $V_{EN} = 0V$                                   | 1.15  | 1.46  | 1.8   | $\mu A$   |
| Under Voltage Lockout Threshold High Going                |   | 2.37  | 2.495 | 2.62  | V         |
| Under Voltage Lockout Threshold Hysteresis                |   |       | 210   |       | mV        |
| Supply current (quiescent)                                | $V_{EN} \leq 0.4V$                              |       | 23    | 36    | $\mu A$   |
| Supply current (operating)                                | $V_{EN} \geq 2.6V$ ; $V_{FB} = 1.4V$            |       | 1.0   | 1.2   | mA        |
| Thermal Shutdown  |   |       | 160   |       | C         |

**Note 1.** Exceeding these ratings may damage the device.

**Note 2.** The device is not guaranteed to function outside its operating rating.

**Note 3.** Measured on approximately 1" square of 1 oz. copper surrounding device leads.

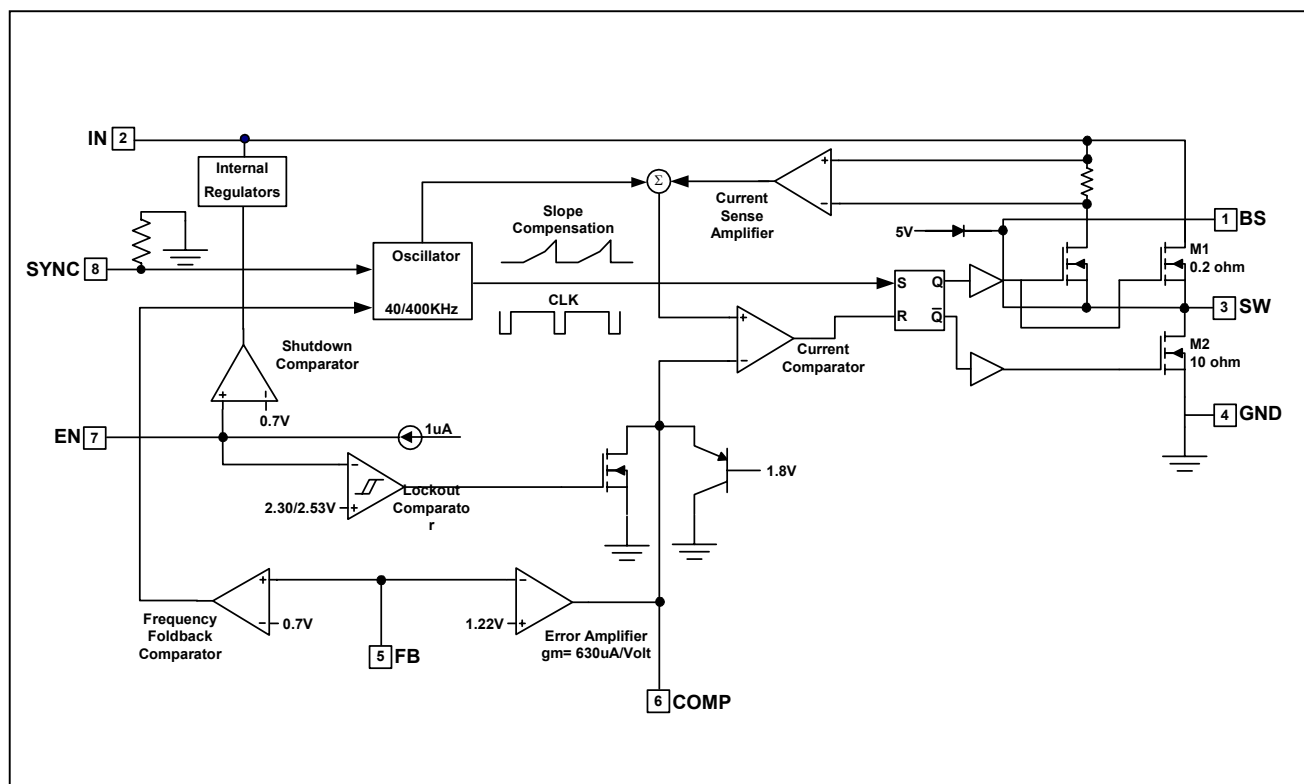
## Pin Descriptions



**Table 1: Pin Designators**

| Pin Number | Pin Name | Description   |
|------------|----------|---|
| 1          | BS       | Bootstrap (C5) - This capacitor is needed to drive the power switch's gate above the supply voltage. It is connected between SW and Bootstrap pins to effect a floating supply across the power switch driver. The voltage across C5 is about 5V and is supplied by the internal +5V supply when the SW pin voltage is low. |
| 2          | IN       | Supply Voltage - The MP1580 operates from a +4.75V to +25V unregulated input. C1 is needed to prevent large voltage spikes from appearing at the input.   |
| 3          | SW       | Switch - This connects the inductor to either IN through M1 or to GND through M2.   |
| 4          | GND      | Ground - This pin is the voltage reference for the regulated voltage. For this reason care must be taken in its layout. This node should be placed outside of the D <sub>SCH</sub> to C1 ground path to prevent switching current spikes to induce voltage noise into the part.   |
| 5          | FB       | Feedback - An external resistor divider from the output voltage to GND, tapped to the FB pin sets the output voltage. To prevent current limit run away during a short circuit fault condition the frequency fold back comparator lowers the oscillation frequency when the FB voltage is below 650mV.                      |
| 6          | COMP     | Compensation - This node is the output of the transconductance error amplifier and the input to the current comparator. Frequency compensation is done at this node by connecting a series R-C to ground. See the compensation section for exact details.   |
| 7          | EN       | Enable/UVLO - A voltage greater than 2.495V enables operation. Leave the input unconnected if unused. An Under Voltage Lockout (UVLO) function can be implemented by the addition of a resistor divider from V <sub>IN</sub> to GND. For complete low current shutdown its needs to be less than 0.7V.                      |
| 8          | SYNC     | Synchronization Input - This pin is used to synchronize the internal oscillator frequency to an external source. There is an internal 11KΩ pull down resistor to GND hence leave the input unconnected if unused.   |

**Figure 2: Functional Block Diagram**



## Functional Description

The MP1580 is a current mode regulator. That is, the compensation pin voltage is proportional to the current delivered to the load. At the beginning of a cycle: the upper transistor M1 is off; the lower transistor M2 on; the COMP pin voltage is higher than the current sense amplifier output; and the current comparator's output is low. The rising edge of the 380KHz CLK signal sets the RS Flip-Flop. Its output turns off M2 and turns on M1 thus connecting the Switch pin and inductor to the Input supply. The increasing inductor current is sensed and amplified by the Current Sense Amplifier. Ramp compensation is summed to Current Sense Amplifier output and compared to the error amplifier output by the Current Comparator. When the Current Sense Amplifier plus Slope Compensation signal exceeds the Comp pin voltage, the RS Flip-

Flop is reset and the chip reverts to its initial M1 off, M2 on state. If the Current Sense Amplifier plus Slope Compensation signal does not exceed the COMP voltage, then the falling edge of the CLK resets the Flip-Flop.

The output of the Error amplifier integrates the voltage difference between the feedback and the 1.22V bandgap reference. The polarity is such that feedback pin voltages lower than 1.22V increases the COMP pin voltage. Since the COMP pin's voltage is proportional to the peak inductor current an increase in its voltage increases current delivered to the output. The lower 10Ω switch ensures that the bootstrap capacitor voltage is charged during light load conditions. External Schottky Diode D1 carries most of the inductor current.

## Application Information

### Sync Pin Operation

The SYNC pin driving waveform should be a square wave with a rise time of less than 20ns. Minimum Hi voltage level is 2.7V. Low level is less than 0.8V. The frequency of the external Sync signal needs to be greater than 445 KHz.

A rising edge on the SYNC pin forces a reset of the oscillator. The upper DMOS is switched off immediately if it is not already off. 250nS later the upper DMOS turns on connecting SW to  $V_{IN}$ .

### Setting the Output Voltage

The output voltage is set using a resistive voltage divider from the output voltage to FB (see Figure 3). The voltage divider divides the output voltage down by the ratio:

$$V_{FB} = V_{OUT} * R2 / (R1 + R2)$$

Thus the output voltage is:

$$V_{OUT} = 1.222 * (R1 + R2) / R2$$

R2 can be as high as 100K $\Omega$ , but a typical value is 10K $\Omega$ . Using that value, R1 is determined by:

$$R1 \sim 8.18 * (V_{OUT} - 1.222) \text{ (K}\Omega\text{)}$$

For example, for a 3.3V output voltage, R2 is 10K $\Omega$ , and R1 is 17K $\Omega$ .

### Inductor

The inductor is required to supply constant current to the output load while being driven by the switched input voltage. A larger value inductor results in less ripple current that in turn results in lower output ripple voltage. However, the larger value inductor has a larger physical size, higher series resistance, and/or lower saturation current. Choose an inductor that does not saturate under the worst-case load conditions. A good rule for determining the inductance is to allow the peak-to-peak ripple current in the inductor to

be approximately 30% of the maximum load current. Also, make sure that the peak inductor current (the load current plus half the peak-to-peak inductor ripple current) is below the TBDA minimum current limit. The inductance value can be calculated by the equation:

$$L = (V_{OUT}) * (V_{IN} - V_{OUT}) / V_{IN} * f * \Delta I$$

Where  $V_{OUT}$  is the output voltage,  $V_{IN}$  is the input voltage, f is the switching frequency, and  $\Delta I$  is the peak-to-peak inductor ripple current. Table 2 lists a number of suitable inductors from various manufacturers.

**Table 2: Inductor Selection Guide**

| Vendor/<br>Model | Core<br>Type | Core<br>Material | Package<br>Dimensions (mm) |      |     |
|------------------|--------------|------------------|----------------------------|------|-----|
|                  |              |                  | W                          | L    | H   |
| Sumida           |              |                  |                            |      |     |
| CR75             | Open         | Ferrite          | 7.0                        | 7.8  | 5.5 |
| CDH74            | Open         | Ferrite          | 7.3                        | 8.0  | 5.2 |
| CDRH5D28         | Shielded     | Ferrite          | 5.5                        | 5.7  | 5.5 |
| CDRH5D28         | Shielded     | Ferrite          | 5.5                        | 5.7  | 5.5 |
| CDRH6D28         | Shielded     | Ferrite          | 6.7                        | 6.7  | 3.0 |
| CDRH104R         | Shielded     | Ferrite          | 10.1                       | 10.0 | 3.0 |
| Toko             |              |                  |                            |      |     |
| D53LC<br>Type A  | Shielded     | Ferrite          | 5.0                        | 5.0  | 3.0 |
| D75C             | Shielded     | Ferrite          | 7.6                        | 7.6  | 5.1 |
| D104C            | Shielded     | Ferrite          | 10.0                       | 10.0 | 4.3 |
| D10FL            | Open         | Ferrite          | 9.7                        | 11.5 | 4.0 |
| Coilcraft        |              |                  |                            |      |     |
| DO3308           | Open         | Ferrite          | 9.4                        | 13.0 | 3.0 |
| DO3316           | Open         | Ferrite          | 9.4                        | 13.0 | 5.1 |

### Input Capacitor

The input current to the step-down converter is discontinuous, and so a capacitor is required to supply the AC current to the step-down converter while maintaining the DC input voltage. A low ESR capacitor is required to keep the noise at the IC to a minimum. Ceramic capacitors are preferred, but tantalum or low-ESR electrolytic capacitors may also suffice.

The input capacitor value should be greater than 10 $\mu$ F. The capacitor can be electrolytic, tantalum or ceramic. However since it absorbs the input switching current it requires an adequate ripple current rating. Its RMS current rating should be greater than approximately 1/2 of the DC load current.

For insuring stable operation C2 should be placed as close to the IC as possible. Alternately a smaller high quality ceramic 0.1 $\mu$ F capacitor may be placed closer to the IC and a larger capacitor placed further away. If using this technique, it is recommended that the larger capacitor be a tantalum or electrolytic type. All ceramic capacitors should be placed close to the MP1583.

#### Output Capacitor

The output capacitor is required to maintain the DC output voltage. Low ESR capacitors are preferred to keep the output voltage ripple low. The characteristics of the output capacitor also affect the stability of the regulation control system. Ceramic, tantalum, or low ESR electrolytic capacitors are recommended. In the case of ceramic capacitors, the impedance at the switching frequency is dominated by the capacitance, and so the output voltage ripple is mostly independent of the ESR. The output voltage ripple is estimated to be:

$$V_{\text{RIPPLE}} \sim 1.4 * V_{\text{IN}} * (f_{\text{LC}}/f_{\text{SW}})^2$$

Where  $V_{\text{RIPPLE}}$  is the output ripple voltage,  $V_{\text{IN}}$  is the input voltage,  $f_{\text{LC}}$  is the resonant frequency of the LC filter,  $f_{\text{SW}}$  is the switching frequency. In the case of tantalum or low-ESR electrolytic capacitors, the ESR dominates the impedance at the switching frequency, and so the output ripple is calculated as:

$$V_{\text{RIPPLE}} \sim \Delta I * R_{\text{ESR}}$$

Where  $V_{\text{RIPPLE}}$  is the output voltage ripple,  $\Delta I$  is the inductor ripple current, and  $R_{\text{ESR}}$  is the equivalent series resistance of the output capacitors.

#### Output Rectifier Diode

The output rectifier diode supplies the current to the inductor when the high-side switch is off. To reduce losses due to the diode forward voltage and recovery times, use a Schottky rectifier.

Table 3 provides the Schottky rectifier part numbers based on the maximum input voltage and current rating.

**Table 3: Schottky Rectifier Selection Guide**

| $V_{\text{IN}}$ (Max) | 2A Load Current |        |
|-----------------------|-----------------|--------|
|                       | Part Number     | Vendor |
| 15V                   | 30BQ15          | 4      |
| 20V                   | B220            | 1      |
|                       | SK23            | 6      |
|                       | SR22            | 6      |
| 26V                   | 20BQ030         | 4      |
|                       | B230            | 1      |
|                       | SK23            | 6      |
|                       | SR23            | 3, 6   |
|                       | SS23            | 2, 3   |

Table 4 lists some rectifier manufacturers.

**Table 4: Schottky Diode Manufacturers**

| # | Vendor                  | Web Site   |
|---|-------------------------|--|
| 1 | Diodes, Inc.            | <a href="http://www.diodes.com">www.diodes.com</a>               |
| 2 | Fairchild Semiconductor | <a href="http://www.fairchildsemi.com">www.fairchildsemi.com</a> |
| 3 | General Semiconductor   | <a href="http://www.gensemi.com">www.gensemi.com</a>             |
| 4 | International Rectifier | <a href="http://www.irf.com">www.irf.com</a>                     |
| 5 | On Semiconductor        | <a href="http://www.onsemi.com">www.onsemi.com</a>               |
| 6 | Pan Jit International   | <a href="http://www.panjit.com.tw">www.panjit.com.tw</a>         |

Choose a rectifier who's maximum reverse voltage rating is greater than the maximum input voltage, and who's current rating is greater than the maximum load current.

### Compensation

The system stability is controlled through the COMP pin. COMP is the output of the internal transconductance error amplifier. A series capacitor-resistor combination sets a pole-zero combination to control the characteristics of the control system.

The DC loop gain is:

$$A_{VDC} = (V_{FB} / V_{OUT}) * A_{VEA} * G_{CS} * R_{LOAD}$$

Where:

$V_{FB}$  is the feedback threshold voltage, 1.222V

$V_{OUT}$  is the desired output regulation voltage

$A_{VEA}$  is the transconductance error amplifier voltage gain, 400 V/V

$G_{CS}$  is the current sense gain, (roughly the output current divided by the voltage at COMP), 3.8 A/V

$R_{LOAD}$  is the load resistance ( $V_{OUT} / I_{OUT}$  where  $I_{OUT}$  is the output load current)

The system has 2 poles of importance, one is due to the compensation capacitor (C3), and the other is due to the output capacitor (C2). These are:

$$f_{P1} = G_{MEA} / (2\pi * A_{VEA} * C3)$$

Where P1 is the first pole, and  $G_{MEA}$  is the error amplifier transconductance (800 $\mu$ S).

and

$$f_{P2} = 1 / (2\pi * R_{LOAD} * C2)$$

The system has one zero of importance, due to the compensation capacitor (C3) and the compensation resistor (R3). The zero is:

$$f_{Z1} = 1 / (2\pi * R3 * C3)$$

If a large value capacitor (C2) with relatively high equivalent-series-resistance (ESR) is used, the zero due to the capacitance and ESR of the output capacitor can be

compensated by a third pole set by R3 and C6. The pole is:

$$f_{P3} = 1 / (2\pi * R3 * C6)$$

The system crossover frequency (the frequency where the loop gain drops to 1, or 0dB) is important. A good rule of thumb is to set the crossover frequency to approximately 1/10 of the switching frequency. In this case, the switching frequency is 385KHz, so use a crossover frequency,  $f_c$ , of 40KHz. Lower crossover frequencies result in slower response and worse transient load recovery. Higher crossover frequencies can result in instability.

**Table 5: Compensation Values for Typical Output Voltage/Capacitor Combinations**

| V <sub>OUT</sub> | C5                                  | R3            | C3    | C4    |
|------------------|-------------------------------------|---------------|-------|-------|
| 2.5V             | 22 $\mu$ F Ceramic                  | 3.9K $\Omega$ | 3.9nF | None  |
| 3.3V             | 22 $\mu$ F Ceramic                  | 4.7K $\Omega$ | 3.3nF | None  |
| 5V               | 22 $\mu$ F Ceramic                  | 7.5K $\Omega$ | 2.2nF | None  |
| 12V              | 22 $\mu$ F Ceramic                  | 10K $\Omega$  | 2.7nF | None  |
| 2.5V             | 47 $\mu$ F SP-Cap                   | 8.2K $\Omega$ | 1.8nF | None  |
| 3.3V             | 47 $\mu$ F SP-Cap                   | 10K $\Omega$  | 1.8nF | None  |
| 5V               | 47 $\mu$ F SP-Cap                   | 10K $\Omega$  | 2.7nF | None  |
| 12V              | 47 $\mu$ F SP-Cap                   | 10K $\Omega$  | 5.6nF | None  |
| 2.5V             | 560 $\mu$ F/6.3V (30m $\Omega$ ESR) | 10K $\Omega$  | 15nF  | 1.5nF |
| 3.3V             | 560 $\mu$ F/6.3V (30m $\Omega$ ESR) | 10K $\Omega$  | 18nF  | 1.5nF |
| 5V               | 470 $\mu$ F/10V (30m $\Omega$ ESR)  | 10K $\Omega$  | 27nF  | None  |
| 12V              | 220 $\mu$ F/25V (30m $\Omega$ ESR)  | 10K $\Omega$  | 27nF  | None  |

### Choosing the Compensation Components

The values of the compensation components given in Table 5 yield a stable control loop for the output voltage and capacitor given. To optimize the compensation components for conditions not listed in Table 5, use the following procedure:

Choose the compensation resistor to set the desired crossover frequency (See Figure 3). Determine the value by the following equation:

$$R3 = 2\pi * C2 * V_{OUT} * f_C / (G_{EA} * G_{CS} * V_{FB})$$

Putting in the know constants and setting the crossover frequency to the desired 40kHz:

$$R3 \approx 6.8 \times 10^7 C2 * V_{OUT}$$

The value of R3 is limited to 10KΩ to prevent output overshoot at startup, so if the value calculated for R3 is greater than 10KΩ, use 10KΩ. In this case, the actual crossover frequency is less than the desired 40kHz, and is calculated by:

$$f_C = R3 * G_{EA} * G_{CS} * V_{FB} / (2\pi * C2 * V_{OUT})$$

or

$$f_C \approx 5.9 / C2 * V_{OUT}$$

Choose the compensation capacitor to set the zero to ¼ of the crossover frequency. Determine the value by the following equation:

$$C3 = 2 / \pi * R3 * f_C \approx 1.59 \times 10^{-5} / R3$$

if R3 is less than 10KΩ, or if R3 = 10KΩ use the following equation:

$$C3 = 4C2 * V_{OUT} / (R3^2 * G_{EA} * G_{CS} * V_{FB})$$

$$C3 \approx 1.08 \times 10^{-5} C_{OUT} V_{OUT}$$

Determine if the second compensation capacitor, C6 is required. It is required if the ESR zero of the output capacitor happens at less than four times the crossover frequency. Or:

$$8\pi * C2 * R_{ESR} * f_C \geq 1$$

Where  $R_{ESR}$  is the equivalent series resistance of the output capacitor.

If this is the case, then add the second compensation resistor. Determine the value by the equation:

$$C6 = C2 * R_{ESR(max)} / R3$$

Where  $R_{ESR(MAX)}$  is the maximum ESR of the output capacitor.

**Example:**

$$V_{OUT} = 5V$$

$$C2 = 22\mu F \text{ Ceramic (ESR} = 10m\Omega)$$

$R3 \approx 6.8 \times 10^7 (22 \times 10^{-6}) (5) = 7480\Omega$ . Use the nearest standard value of 7.5KΩ.

$C3 \approx 1.59 \times 10^{-5} / 7.5K\Omega = 2.12nF$ . Use the nearest standard value of 2.2nF.

$2\pi * C2 * R_{ESR} f_C = .055$  which is less than 1, therefore no second compensation capacitor is required.

**Table IV. Recommended components for standard output voltages**

| $V_{OUT}$ | R1     | L1 minimum |
|-----------|--------|------------|
| 1.22V     | 0Ω     | 6.8μH      |
| 1.5V      | 2.32KΩ | 6.8μH      |
| 1.8V      | 4.75KΩ | 10μH       |
| 2.5V      | 10.5KΩ | 10μH       |
| 3.3V      | 16.9KΩ | 15μH       |
| 5.0V      | 30.9KΩ | 22μH       |

Figure 3: MP1580 with Murata 22 $\mu$ F / 10V Ceramic Output

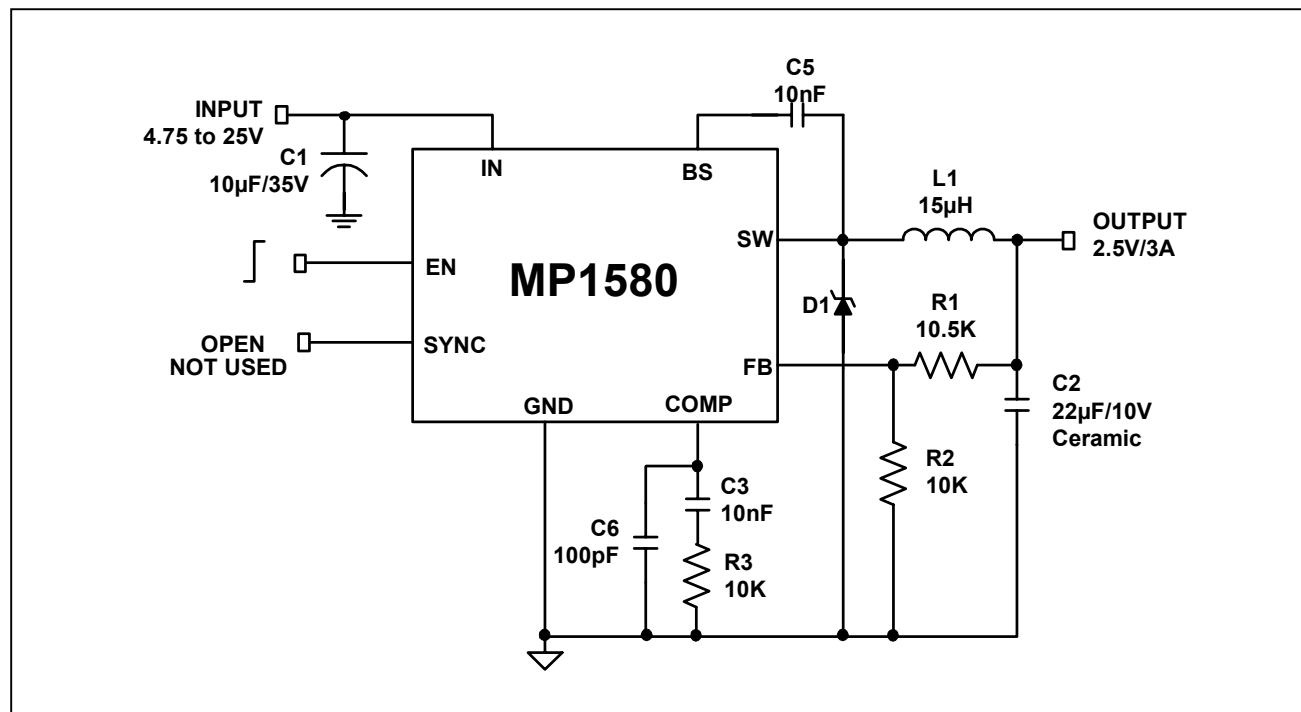
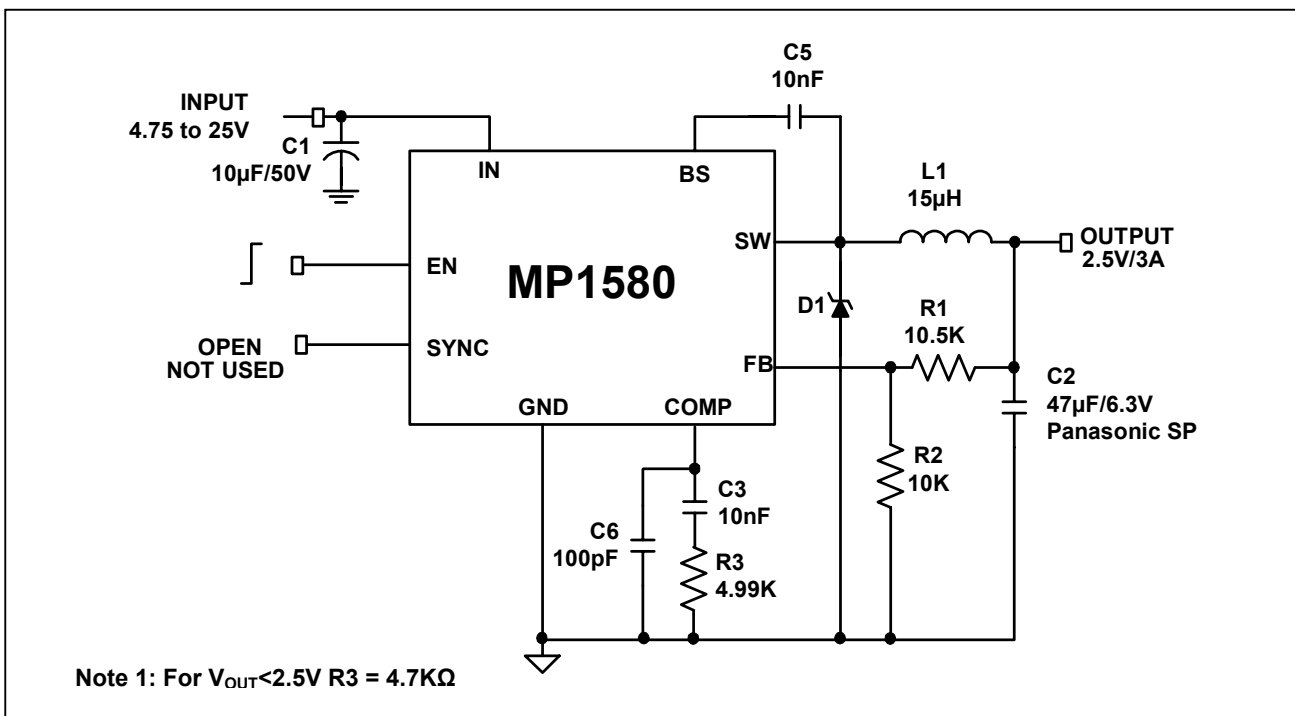
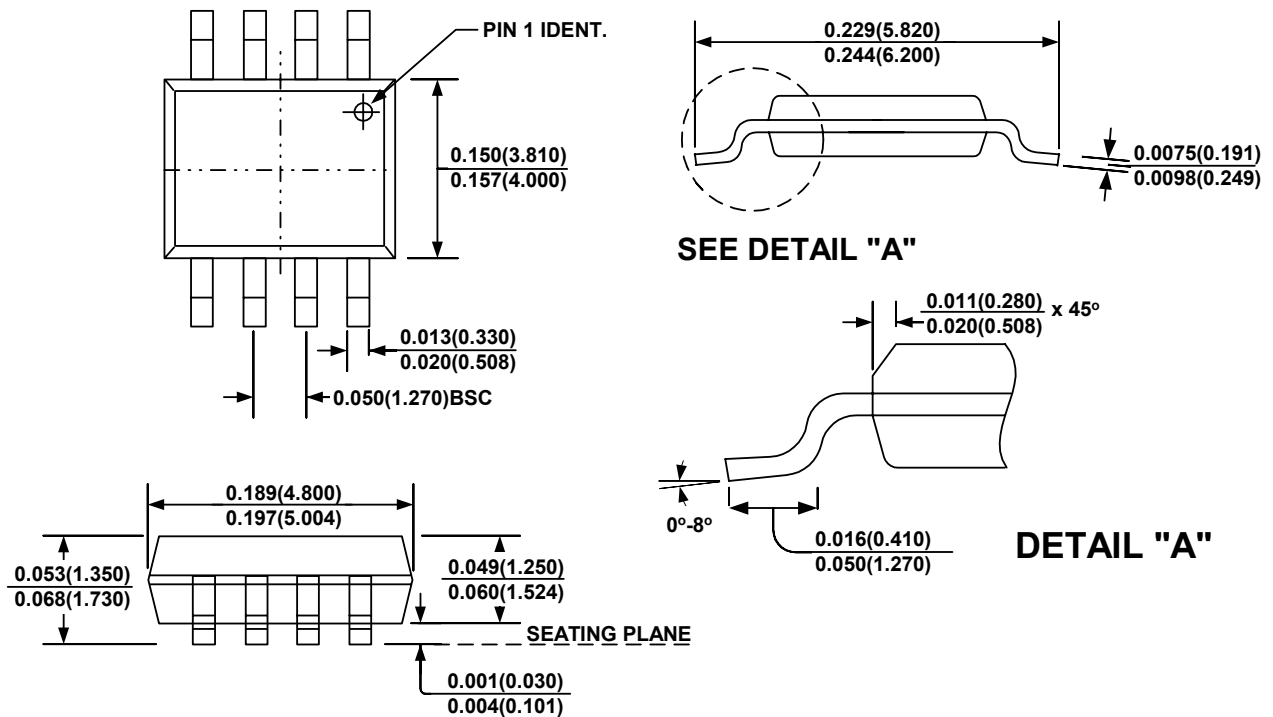


Figure 4: MP1580 with Panasonic 47 $\mu$ F / 6.3V Special Polymer Output Capacitor



## Packaging

### SOIC8



**NOTE:**

1) Control dimension is in inches. Dimension in bracket is millimeters.

**NOTICE:** MPS believes the information in this document to be accurate and reliable. However, it is subject to change without notice. Please contact the factory for current specifications. No responsibility is assumed by MPS for its use or fit to any application, nor for infringement of patent or other rights of third parties.